Diode Semiconductor Device - Page 1 of 1



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Inclosure M	
Plastic	
Overall Len	-
0.049 inches	
Overall Heig	
0.030 inches	
Overall Wid	
0.033 inches	
	or Which Designed:
Transient su	
End Applica	
	eiver rt-1523 (c) /u
Mounting M	etiloa:
Terminal	ator Matarial
	ctor Material:
Silicon	ing In Volte Per Characteristic
-	ing In Volts Per Characteristic:
	wn voltage, dc
	ng Per Characteristic:
	peak pulse input power over the specified operating temperature range e Rating In Picofarads:
100.0	s having in Ficulataus.
	perating Tempurature Per Measurement Point:
	es celsius ambient air
Product Nai	
	tor device, diode, surface mount
	rpe And Quantity:
2 bonding pa	
Shelf Life:	
N/a	
Unit Of Mea	sure:
Demilitariza	tion:
No	
Fiig:	
A110a0	